### GENERAL DESCRIPTION:-

The 8550 is a PNP epitaxial silicon planar transistor designed for use in the audio output stage and converter/inverter circuits. Complementary to 8050.

# ABSOLUTE MAXIMUM RATINGS (Note 1)

Maximum Temperatures

Storage Temperature  $-55^{\circ}$ C to  $+135^{\circ}$ C 135°C Operating Temperature Lead Temperature (soldering, 10 seconds time limit) 230°C

Maximum Power Dissipation

Total Dissipation at 25°C Ambient Temperature (Note 2) 1.0 Watt Total Dissipation at 25°C case temperature (Note 2) 3.0 Watt

Maximum Voltage

VCBO Collector to Base Voltage 30V VCEO Collector Emitter Voltage (Note 3) 25V VEBO Emitter to Base Voltage 6V 1.5A Collector current (Continuous)

SYMBOL	CHARACTERISTICS	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
HFE1	DC current gain (Note 4)	85		300		Ic = 100mA Vce = 1V
HFE2	DC current gain	40				Ic = 800mA Vce = 1V
VCE (SAT)	Collector Saturation Voltage (Note 4) 0.2 0.5		V	Ic = 800mA Ib = 80mA		
VBE (SAT)	Base-Saturation Voltage (Note 4)		0,92	1.2	V	Ic = 800mA Ib = 80mA
LVceo	Colector to Emitter breakdown Voltage (Note 3 & 4)	25			٧	Ic = 10mA Ib = 0
BVcbo	Collector to Base breakdown Voltage	30			V	Ic = 100uA Ie = 0
BVebo	Emitter to Base breakdown Voltage	6			V	le = 100uA lc = 0
lcbo	Collector cut off current			0.1	uA	Vcb= 20V le = 0
hfe	High frequency current gain	1.0				Ic = 50mA Vce = 10V
	·					f = 100MHz
Ccb	Collector to Base capacitance			40	ρF	Vcb= 10V Ic = 0
						f = 1MHz

### NOTES:

- These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
- These ratings give a maximum junction temperature of 145°C, junction to ambient thermal resistance of 120°C/ Watt (derating factor of 8.33mW/°C) and junction to case thermal resistance of 40°C/W (derating factor of 25mW/°C)
- Rating refers to a high-current point where collector-to-emitter voltage is lowest.
- Pulse Conditions: length  $\leq$  300 us; duty cycle  $\leq$  2%

## CLASSIFICATION OF HFE GROUPS

GROUP	MIN	MAX /	TEST CONDITION
В	85	160	Ic = 100mA
С	120	200	Ic = 100mA
D	160	300	Ic = 100mA



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